



浙江芯芯电子有限公司  
ZHEJIANG XINXIN ELECTIRICAL CO., LTD.

# 产品规格书

## Specification of Products

产品名称：平板型

产品型号：400A

浙江芯芯电子有限公司

ZHEJIANG XINXIN ELECTIRICAL CO., LTD.

地址：浙江省缙云县壶镇镇浙江丽缙五金科技产业园苍山区块内

电话：13857067071

邮编：321404

E-mail:247145749@qq.com

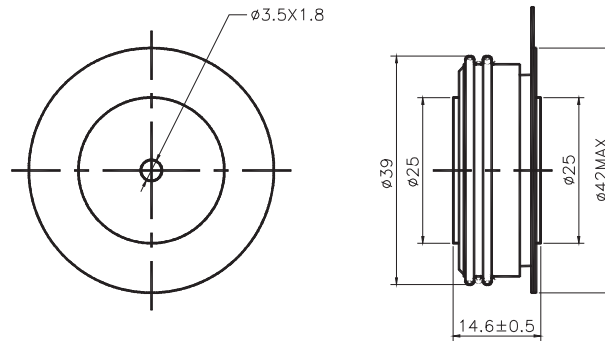
<http://www.zjxxdz1.com>

拟制	审核	核准
丁国盛	李园利	麻伟阳

版本号：04 更新日期：2022.6.28

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>J</sub> (C)	VALUE			UNIT
				Min	Type	Max	
I <sub>F(AV)</sub>	Mean forward current	180 half sinewave 50Hz Double side cooled, T <sub>S</sub> =55C	150			929	A
I <sub>F(AV)</sub>	Mean forward current	180 half sinewave 50Hz Double side cooled, T <sub>S</sub> =90C	150			667	A
V <sub>RRM</sub>	Repetitive peak reverse voltage	V <sub>RRM</sub> tp=10ms V <sub>RSM</sub> = V <sub>RRM</sub> +100V	150	1100		2000	V
I <sub>RRM</sub>	Repetitive peak current	at V <sub>RRM</sub>	150			30	mA
I <sub>FSM</sub>	Surge forward current	10ms half sine wave	150			12.1	KA
I <sup>2</sup> T I	<sup>2</sup> T for fusing coordination	V <sub>R</sub> =0.6V <sub>RRM</sub>				729	A <sup>2</sup> s*10 <sup>3</sup>
V <sub>FO</sub>	Threshold voltage		150			1.06	V
r <sub>F</sub>	Forward slop resistance					0.35	mΩ
V <sub>FM</sub>	Peak onstate voltage I	T <sub>M</sub> =1930A, F=7KN	150			1.74	V
I <sub>m</sub>	Reverse recovery current		150			80	A
t <sub>rr</sub>	Reverse recovery time	I <sub>TM</sub> =1000A, tp= 1000 s, di/dt=-40A/s, V <sub>R</sub> =50V				4.0	s
Q <sub>rr</sub>	Recovery charge					160	C
R <sub>th(j-h)</sub>	Thermal resistance Junction to heatsink	At 180° sine double side cooled Clamping force 7.0KN				0.055	C/W
F <sub>m</sub>	Mounting force			5.3		10	KN
T <sub>stg</sub>	Stored temperature			-40		160	C
W <sub>t</sub>	Weight				80		g
Outline	ZT25aT						

Outline



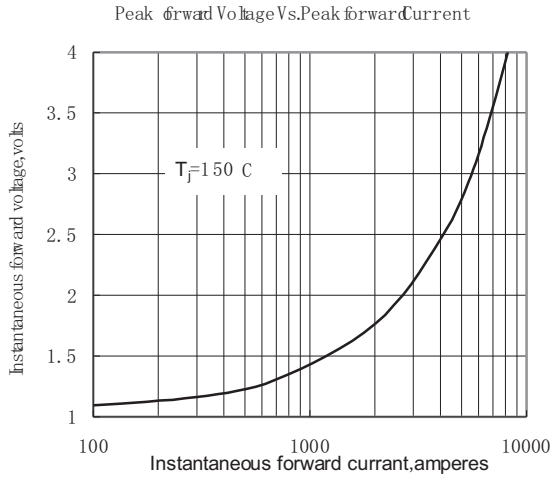


Fig. 1

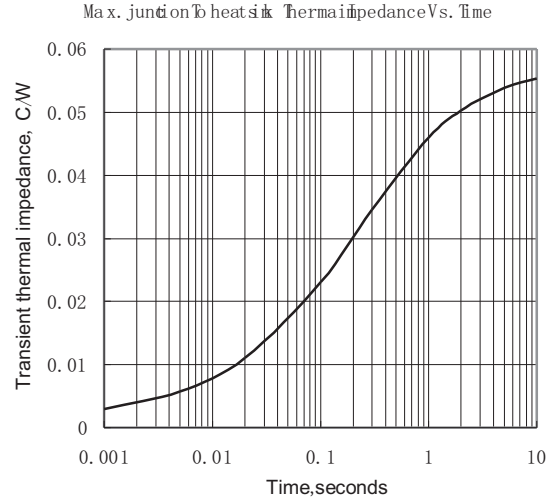


Fig. 2

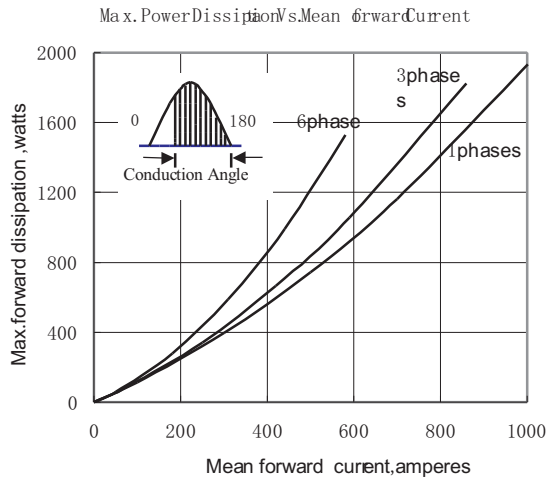


Fig. 3

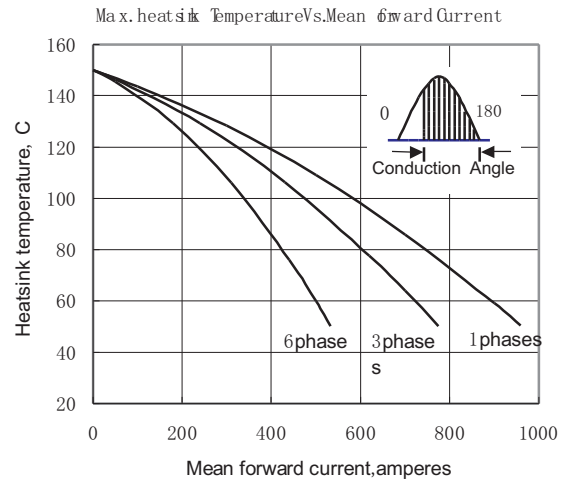


Fig. 4

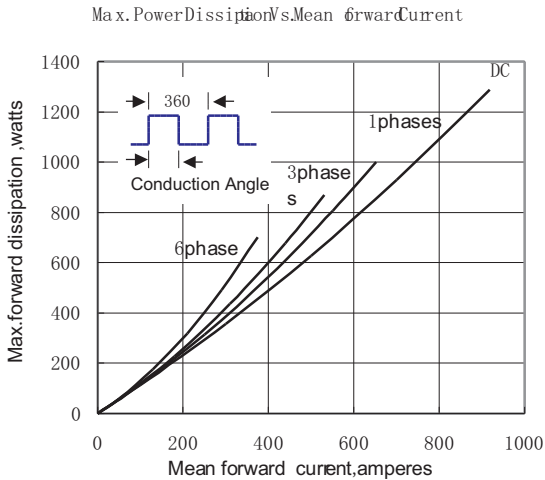


Fig. 5

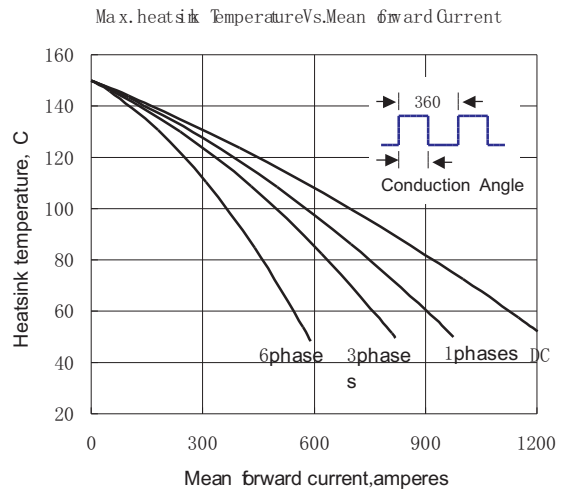


Fig. 6